NSN 5961-00-780-8245

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-780-8245
Inclosure Material:
Metal
Overall Length:
0.380 inches
Terminal Length:
0.420 inches
Overall Diameter:
0.505 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
25.0 breakover voltage, dc
Current Rating Per Characteristic:
24.00 amperes source cutoff current of standard range
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0